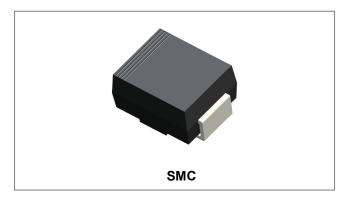






SK34 SCHOTTKY RECTIFIER



Features

- Schottky Barrier Chip
- Guard Ring Die Construction for Transient Protection
- High Current Capability
- Low Power Loss, High Efficiency
- High Surge Current Capability
- For Use in Low Voltage, High Frequency Inverters, Free Wheeling, and Polarity Protection Applications
- This is a Pb Free device
- All SMC parts are traceable to the wafer lot
- Additional testing can be offered upon request

Circuit Diagram



Applications

- Switching power supply
- Converters
- · Free-Wheeling diodes
- Reverse battery protection

Maximum Ratings:

Characteristics	Symbol	Condition	Max.	Units
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	V _{RRM} V _{RWM} V _R	-	40	V
Average Rectified Forward Current	I _{F (AV)}	50% duty cycle @T _C =105°C, rectangular wave form	3	Α
Peak One Cycle Non-Repetitive Surge Current	I _{FSM}	8.3ms, Half Sine pulse, T _c = 25 °C	75	Α

Electrical Characteristics:

Characteristics	Symbol	Condition	Тур.	Max.	Units
Forward Voltage Drop*	V _{F1}	@ 3A, Pulse, T _J = 25 °C	0.58	0.63	V
	V _{F1}	@ 3A, Pulse, T _J = 125 °C	0.50	0.57	V
Reverse Current*	I _{R1}	@V _R = rated V _R , T _J = 25 °C	0.01	50	uA
	I _{R2}	@V _R = rated V _R , T _J = 100 °C	-	10	mA
Junction Capacitance	Ст	$@V_R = 5V, T_C = 25 \text{ °C}, f_{SIG} = 1MHz$	45	150	pF
Series Inductance	Ls	Measured lead to lead 5 mm from package body	8.0	-	nH
Voltage Rate of Change	dv/dt	-	-	10,000	V/μs

^{*} Pulse width < 300 µs, duty cycle < 2%



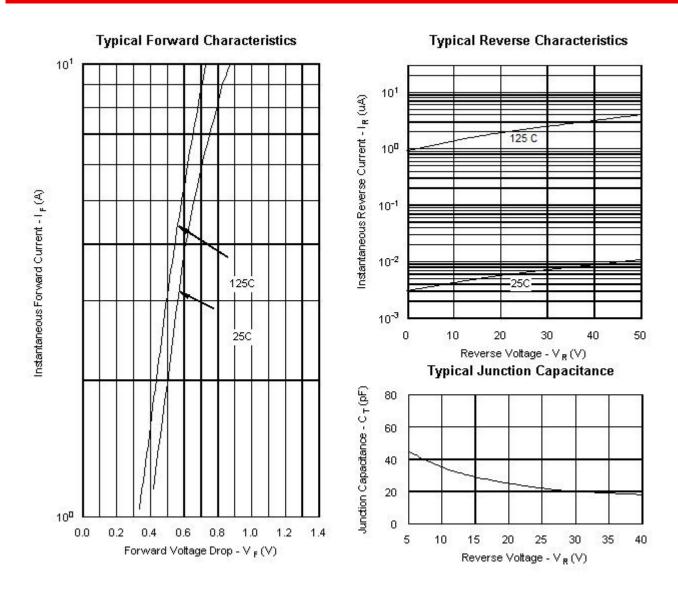




Thermal-Mechanical Specifications:

Characteristics	Symbol	Condition	Specification	Units
Junction Temperature	TJ	-	-55 to +150	°C
Storage Temperature	T _{stg}	-	-55 to +150	°C
Repetitive Peek Reverse Current	I _{RRM}	Tp=2us F=1KHZ square	1	Α
Repetitive Peek Avalanche Power	P _{ARM}	Tp=2us Tj=25℃	1300	W
Approximate Weight	wt	-	0.21	g

Ratings and Characteristics Curves



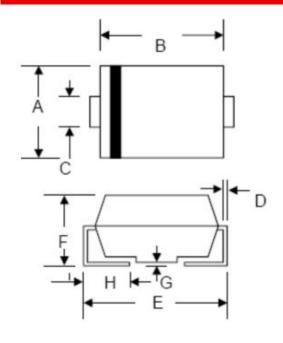
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Mechanical Dimensions SMC



SYMBOL	Millimeters		Inches		
STIVIBUL	Min.	Max.	Min.	Max.	
А	5.59	6.22	0.220	0.245	
В	6.60	7.11	0.260	0.280	
С	2.75	3.25	0.108	0.128	
D	0.152	0.305	0.006	0.012	
E	7.75	8.25	0.305	0.325	
F	2.00	2.95	0.079	0.116	
G	0.051	0.203	0.002	0.008	
Н	0.76	1.60	0.030	0.063	

Ordering Information

Device	Package	Shipping	
SK34	SMC	3000pcs / reel	

For information on tape and reel specifications, including part orientation and tape sizes, please refer to our tape and reel packaging specification.

Marking Diagram

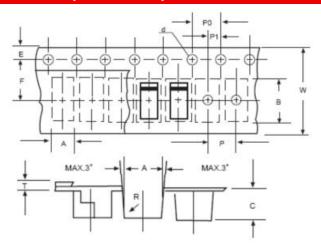
SK34 xxxxx Where XXXXX is YYWWL

SK = Device Type 3 = Forward Current (3A) 4 = Reverse Voltage (40V) YY = Year WW = Week

Cautions: Molding resin Epoxy resin UL:94V-0

= Lot Number

Carrier Tape & Reel Specification SMC



SYMBOL	Millimeters		
STIVIBUL	Min.	Max.	
Α	5.90	6.10	
В	8.20	8.40	
С	2.40	2.60	
d	1.40	1.60	
E	1.40	1.60	
F	7.60	7.70	
Р	7.90	8.10	
P0	3.90	4.10	
P1	3.90	4.10	
T	-	0.600	
W	15.80	16.20	

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